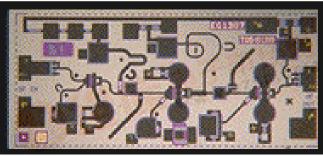


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Key Features and Performance
0.25um pHEMT Technology
23-29 GHz Frequency Range

Advance Product Information May 16, 2000

Ka Band Low Noise Amplifier TGA1307-EPU



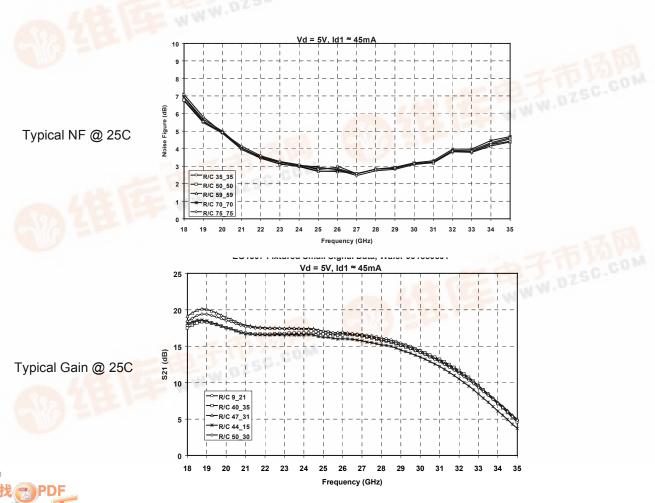
Chip Dimensions 2.54 mm x 1.15 mm

• 3.1 dB Nominal Noise Figure 28GHz

- 17 dB Nominal Gain
- OTOI > 22dBm
- 5V, 50 mA Self-Bias

Primary Applications

- Point-to-Point Radio
- Point-to-Multipoint Communications



Note: Devices designated as EPU are typically early in their characterization process prior to finalizing all electrical and process

df.cspecifications. Specifications subject to change without notice

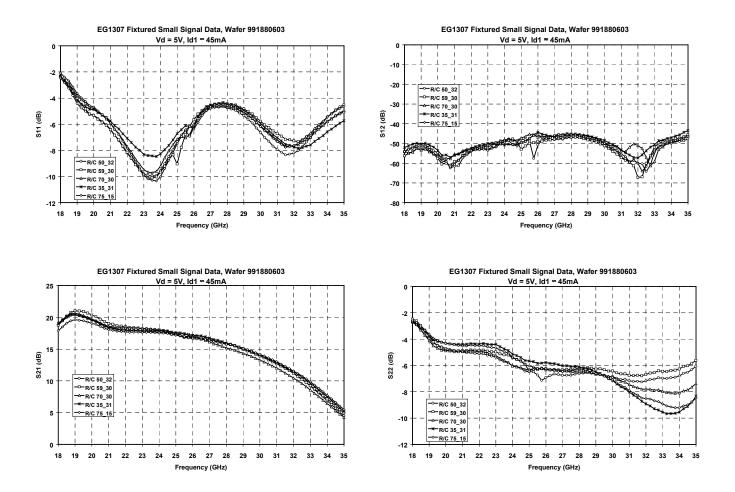




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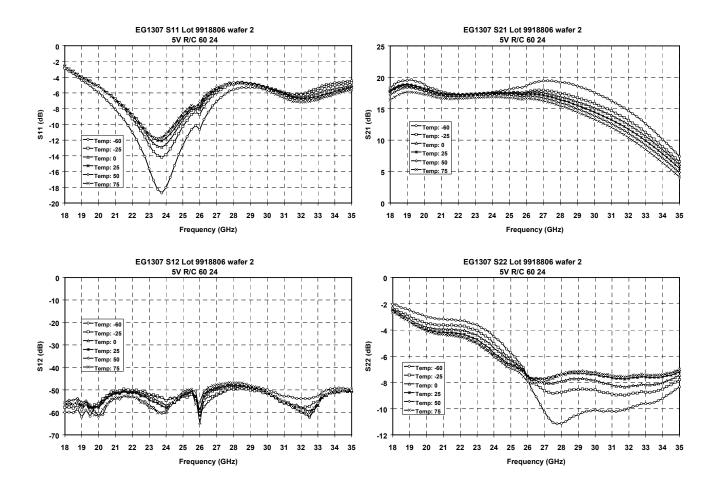


Typical Small Signal S-parameters at 25C.



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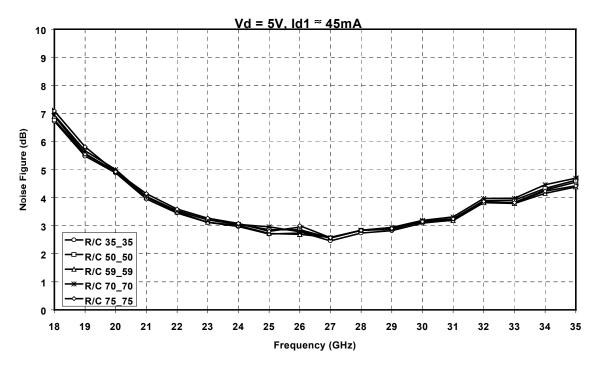


Small Signal S-parameters over temperature.



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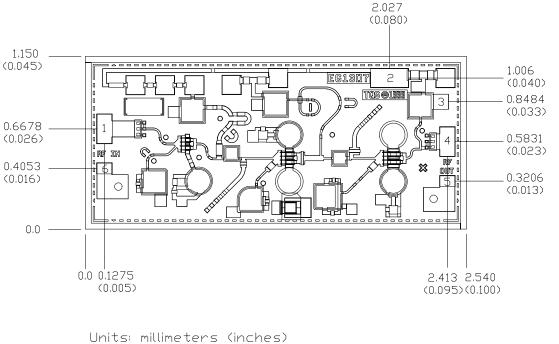


Typical Noise Figure - 5 devices



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Units: millimeters (inches) Thickness: 0.1016 (0.004) (reference only) Chip to bond pad dimensions are shown to center of bond pad Chip size tolerance: +/- 0.051 (0.002)

Bond	Pad	#1	(RF Input)	$0.105 \times$	0,200 (0,004 × 0,008)
Bond	Pad	#2	(Vd)	$0.130 \times$	0.253 (0.005 × 0.010)
Bond	Pad	#3	(GND)	$0.100 \times$	0.100 (0.004 × 0.004)
Bond	Pad	#4	(RF Output)	$0.105 \times$	0.200 (0.004 × 0.008)
Bond	Pad	#5	(GND)	0.075 ×	0,105 (0,003 × 0,004)
Bond	Pad	#6	(GND)	$0.075 \times$	0.105 (0.003 × 0.004)

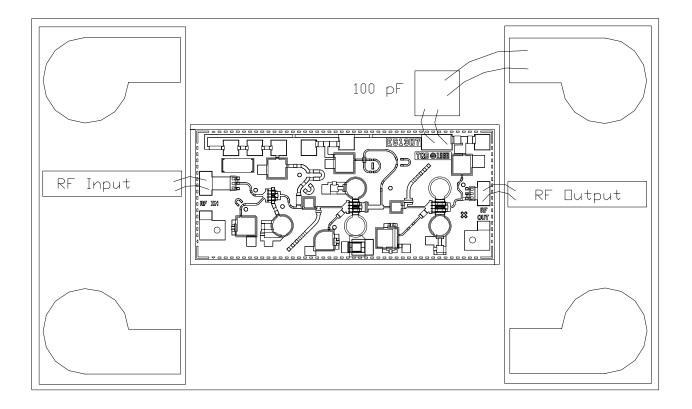
TGA1307-EPU - Mechanical Drawing



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TGA1307



TGA1307-EPU - Recommended Assembly Drawing



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Assembly Process Notes

Reflow process assembly notes:

- AuSn (80/20) solder with limited exposure to temperatures at or above 300°C
- alloy station or conveyor furnace with reducing atmosphere
- no fluxes should be utilized
- coefficient of thermal expansion matching is critical for long-term reliability
- storage in dry nitrogen atmosphere

Component placement and adhesive attachment assembly notes:

- vacuum pencils and/or vacuum collets preferred method of pick up
- avoidance of air bridges during placement
- force impact critical during auto placement
- organic attachment can be used in low-power applications
- curing should be done in a convection oven; proper exhaust is a safety concern
- microwave or radiant curing should not be used because of differential heating
- coefficient of thermal expansion matching is critical

Interconnect process assembly notes:

- thermosonic ball bonding is the preferred interconnect technique
- force, time, and ultrasonics are critical parameters
- aluminum wire should not be used
- discrete FET devices with small pad sizes should be bonded with 0.0007-inch wire
- maximum stage temperature: 200°C

GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.